



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Jack H. Yuan et al.
Title: Non-Volatile Memory Cell Array Having Discontinuous Source and Drain Diffusions Contacted by Continuous Bit Line Conductors and Methods of Forming
Application No.: 10/822,966 Filing Date: April 12, 2004
Examiner: Le, Thao P. Group Art Unit: 2818
Docket No.: SNDK.217US2 Conf. No.: 3615

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I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on April 28, 2005

Mary S. Buggs
Signature

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

RESPONSE TO OFFICE ACTION AND AMENDMENT

Sir:

This is in response to the non-final Office Action dated February 4, 2005.

Claim Amendments are reflected in the listing of claims, which begins on page 2 of this paper.

Remarks begin on page 6 of this paper.

Reconsideration is respectfully requested.